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FGP15N60UNDF 600 V, 15 A **Short Circuit Rated IGBT**

Features

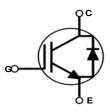
- Short Circuit Rated 10us
- High Current Capability
- High Input Impedance
- Fast Switching
- **RoHS** Compliant •

Applications

• Sewing Machine, CNC, Home Appliances, Motor Control







Using advanced NPT IGBT technology, Fairchild's the NPT IGBTs offer the optimum performance for low-power inverter-

driven applications where low-losses and short-circuit rugged-

ness features are essential, such as sewing machine, CNC,

General Description

motor control and home appliances.

Absolute Maximum Ratings

Symbol	Descriptio	n	Ratings	Unit
V _{CES}	Collector to Emitter Voltage		600	V
V _{GES}	Gate to Emitter Voltage		± 20	V
Ι _C	Collector Current	@ T _C = 25 ^o C	30	А
	Collector Current	@ T _C = 100°C	15	А
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25 ^o C	45	A
I _F	Diode Forward Current	@ T _C = 25°C	15	A
	Diode Forward Current	@ T _C = 100 ^o C	7.5	А
P _D	Maximum Power Dissipation	@ T _C = 25°C	178	W
' ט	Maximum Power Dissipation	@ T _C = 100°C	71	W
TJ	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C

Notes: 1: Repetitive test , Pulse width=100 usec , Duty=0.2, V_{GF}=13.5 V

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Unit
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case		0.7	°C/W
$R_{\theta JC}(Diode)$	de) Thermal Resistance, Junction to Case		2.3	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (PCB Mount)(2)		62.5	°C/W

Device Marking Device Pa		Package			Tape Width		Quantity 50ea	
Electric	al Char	acteristics of t	he IGBT T _{C=2}	5°C unless otherwise noted				
Symbol		Parameter		Conditions	Min.	Тур.	Max.	Uni
Off Charac	teristics							
BV _{CES}		to Emitter Breakdown Vo	oltage V _{GE} = 0 V, I	c = 250 μA	600	_	-	V
I _{CES}		Cut-Off Current	$V_{CE} = V_{CES}$		-	-	1	mA
I _{GES}		age Current	V _{GE} = V _{GES}		-	-	±10	μA
On Charac	torictics				I		L	1
V _{GE(th)}		shold Voltage	I _C = 15 mA,	$V_{CE} = V_{CE}$	5.5	6.8	8.5	V
· GE(III)			I _C = 15 A, V _c		-	2.2	2.7	V
V _{CE(sat)}	Collector	Collector to Emitter Saturation Voltage		_{GE} = 15 V,	_	2.7		-
				$T_{\rm C} = 125^{\rm o}{\rm C}$		2.1	-	V
Dynamic C	haracteris	tics						
C _{ies}	Input Cap				-	619	-	pF
C _{oes}	Output Ca	apacitance	$V_{CE} = 30 V_{,}$	$V_{GE} = 0 V,$	-	80	-	pF
C _{res}	Reverse 7	Fransfer Capacitance	f = 1 MHz		-	24	-	pF
Switching	Charactori	stics				-	-	
t _{d(on)}	1	Delay Time			-	9.3	-	ns
t _r	Rise Time	•		-		9.8	_	ns
t _{d(off)}		Delay Time	V _{CC} = 400 \	/ I _α – 15 Δ	_	54.8	-	ns
t _f	Fall Time	,	R _G = 10 Ω,	V _{GE} = 15 V,	-	9.9	12.8	ns
E _{on}	Turn-On S	Switching Loss	Inductive Lo	bad, $T_C = 25^{\circ}C$	-	0.37	-	mJ
E _{off}		Switching Loss			-	0.067	-	mJ
E _{ts}	Total Swit	ching Loss			-	0.44	-	mJ
t _{d(on)}	Turn-On [Delay Time			-	8.9	-	ns
t _r	Rise Time	9			-	9.9	-	ns
t _{d(off)}	Turn-Off	Delay Time	V _{CC} = 400 \	/, I _C = 15 A,	-	56.6	-	ns
t _f	Fall Time		R _G = 10 Ω,	V _{GE} = 15 V,	-	13.2	-	ns
Eon	Turn-On S	Switching Loss	Inductive Lo	oad, T _C = 125ºC	-	0.54	-	mJ
E _{off}	Turn-Off S	Switching Loss			-	0.11	-	mJ
E _{ts}	Total Swit	ching Loss			-	0.65	-	mJ
T _{sc}	Short Circ	cuit Withstand Time	R _G = 100 Ω	$V_{CC} = 350 \text{ V},$ $R_G = 100 \Omega, V_{GE} = 15 \text{ V},$ $T_C = 150^{\circ}\text{C}$		-	-	μs

Electrical Characteristics of the IGBT $T_{C} = 25^{\circ}C$ unless otherwise noted

Qg	Total Gate Charge		-	43	-	nC
Q _{ge}	Gate to Emitter Charge	V _{CE} = 400 V, I _C = 15 A, V _{GE} = 15 V	-	6	-	nC
Q _{gc}	Gate to Collector Charge	VGE - 10 V	-	26	-	nC

Electrical Characteristics of the Diode $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit
V _{FM} Diod	Diode Forward Voltage	I _F = 15 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.6	2.2	V
			T _C = 125°C	-	1.5	-] [
t _{rr}	Diode Reverse Recovery Time	I _F =15 A, dI _F /dt = 200 A/μs	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	82.4		ns
11			T _C = 125°C	-	142	-	
Q.,	Q _{rr} Diode Reverse Recovery Charge		$T_{C} = 25^{\circ}C$	-	213	-	nC
∝ rr			T _C = 125°C	-	541	-	

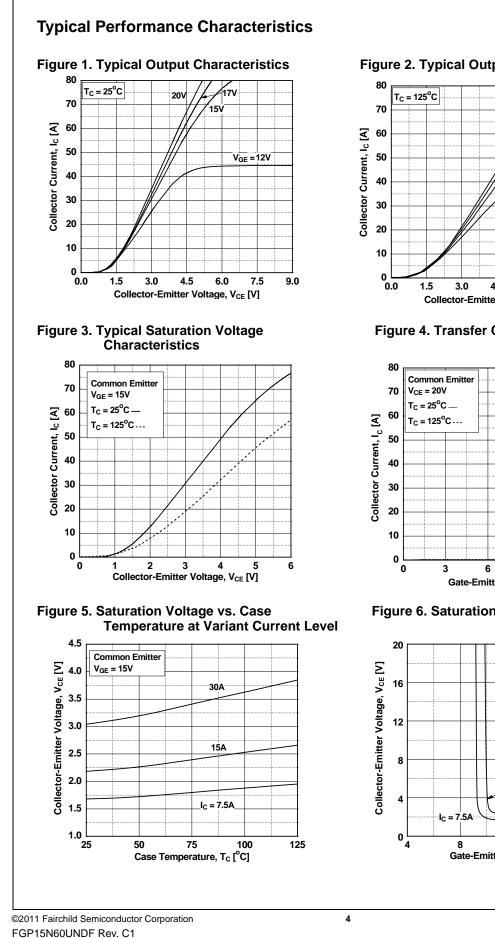
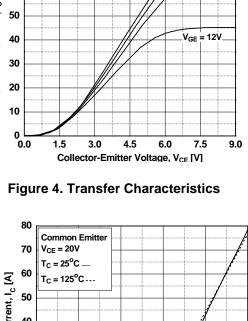


Figure 2. Typical Output Characteristics

17V-

15V

20V



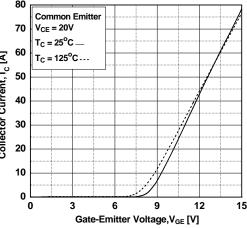
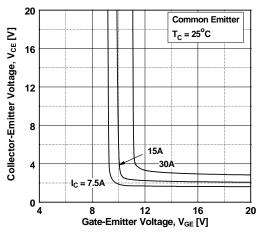


Figure 6. Saturation Voltage vs. V_{GE}



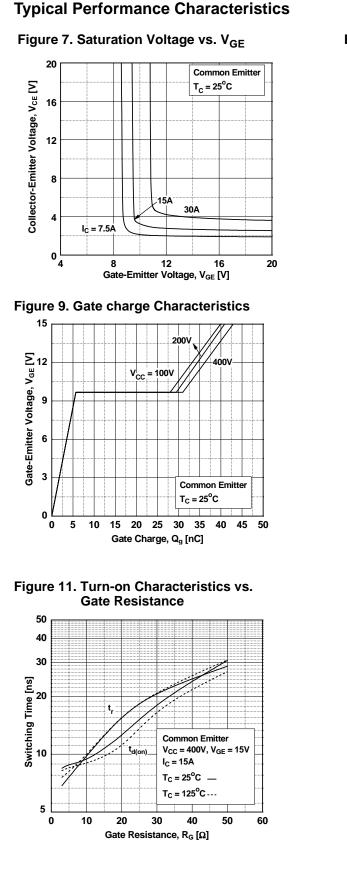
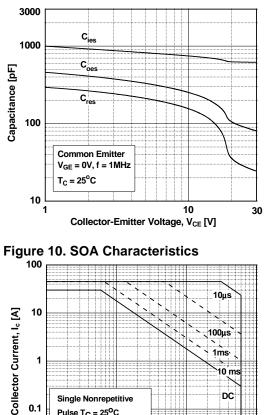


Figure 8. Capacitance Characteristics



1ms

100

Collector-Emitter Voltage, V_{CE} [V]

10 m DC

1000

Figure 12. Turn-off Characteristics vs. Gate Resistance

10

Single Nonrepetitive

linearly with increase

Pulse T_C = 25^oC Curves must be derated

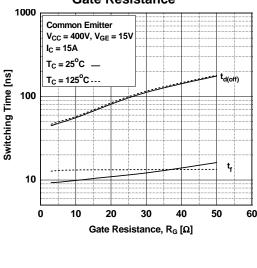
in temperature

1

0.1

0.01

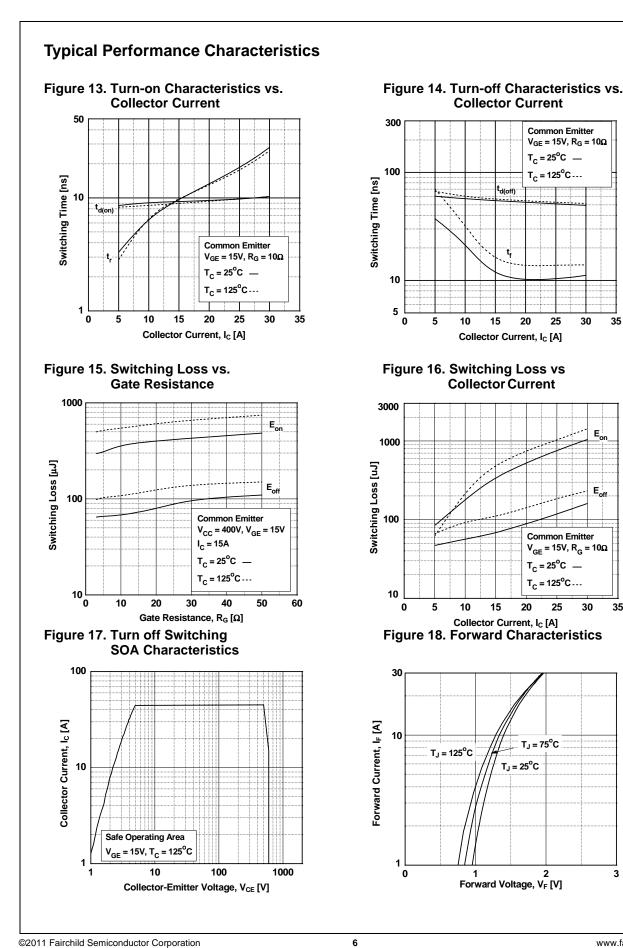
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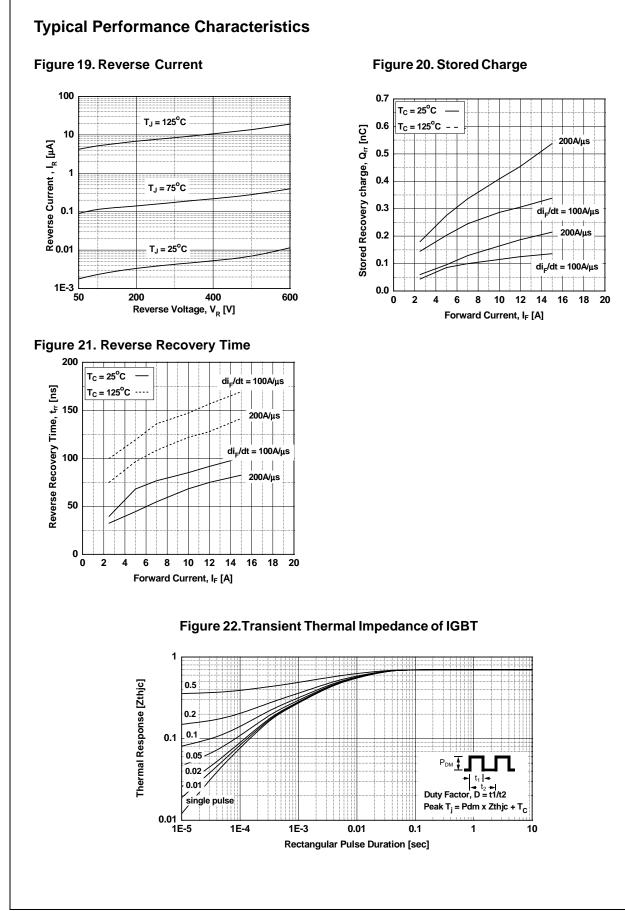
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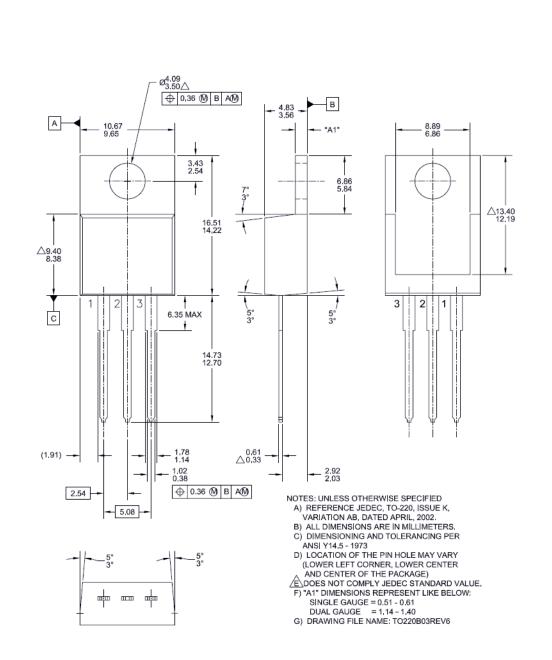


Figure 23. TO-220 3L - TO-220, MOLDED, 3LEAD, JEDEC VARIATION AB

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Dimensions in Millimeters

Mechanical Dimensions



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